

SINGLE BAR DIODE LASER MODULE

780 to 830 nm, Conduction-Cooled

Based on Coherent's legendary Aluminum-free Active Area (AAA™) epitaxy, Coherent 780-830 nm conduction cooled laser bar packages (CCPs) provide unsurpassed reliability and performance. Standard options include 808 nm 60W 18% fill factor bars and 808 nm 80W 28% fill factor bars rated to >20k hours lifetime. Coherent's PulseLife™ technology option, based on AuSn tele- com-grade solder, is available for applications requiring hard-pulsed operation or high temperatures. Low smile configurations are available upon request. Specifications and options—including power, wavelength, and optical delivery—can be tailored to your demands



FEATURES

- Unique AAA epitaxial technology for highest reliability and lifetime
- PulseLife technology option for hard pulsed operation
- Up to 80W from a 28% fill factor bar
- Up to 60W from an 18% fill factor bar
- Low smile options available
- Lifetime >20,000 hours
- ROHS compliant

APPLICATIONS

- Laser Pumping
- Medical
- Materials Processing
- Illumination

Single Bar Diode Laser Module

Device Specifications ^{1,2,3,4,5}	18% fill factor bars (19 x 90 μm emitters)	
	60W 18FF	60W 18FF PulseLife
Intended Operation Mode	CW or QCW	Hard pulsed, CW, or QCW
Optical Output Power (W)	60	
Pulsewidth (μs)	-	
Duty Cycle (%)	-	
Fill Factor (%)	18	
Number of Emitters	19	
Emitter Width (μm)	90	
Emitter-to-Emitter Pitch (μm)	500	
Centroid Wavelength Available ⁶ (nm)	780 to 830	
Centroid Wavelength, Standard (nm)(at 25°C)	808 ±3	
Spectral Width, Standard (nm)(FWHM)	≤3	
Wavelength Temperature Coefficient (nm/°C)	0.28	
Polarization	TE	
Fast Axis Divergence (degrees)(unlensed)(FWHM)	29	
Fast Axis Divergence (degrees)(lensed)(FWHM)	≤1	
Slow Axis Divergence (degrees)(FWHM)	≤10	
Threshold Current (A)	8 typical	
Operating Current (A)	≤61 (56 typical)	≤62 (58 typical)
Operating Voltage (V)	≤2.0	
Operating Temperature ⁷ (°C)	25	
Operating Temperature Range (°C)	15 to 35	
Storage Temperature Range (°C)	-40 to +60	

Notes:

- Specifications listed here are at beginning of life. Operating current at end of life is 120% the operating current at beginning of life.
- CW operation refers to an operating mode in which the diode lases continuously for multiple minutes at a time or longer
- QCW (quasi-continuous wave) operation refers to an operating mode in which the diode lases only in very short pulses, i.e., <1 ms long, typically at repetition rates of several Hz to kHz.
- Hard pulsed operation refers to an operating mode in which the diode is repeatedly turned on and off - full current to zero current - with pulsewidths longer than several milliseconds.
- Please consult the factory for any needs not listed here, including the following options:
 - Centroid wavelength and spectral width requirements other than listed here
 - Optical output powers other than listed here
 - Low smile options.
- Contact factory for availability.
- Operating temperature is measured at the base of the package. The recommended operating temperature range is 15-35°C.

Operation Notes:

- Unit requires an adequate heat sink. Failure to supply an adequate heat sink will destroy the unit. Indium foil should be used between base of diode and heatsink to ensure good thermal contact.
- Torque applied to mounting screws should be controlled carefully, using a torque wrench. For 6-32 mounting screws, use 8 in-lbs (with Indium foil). For M4 mounting screws, use 9 in-lbs (with Indium foil).
- ESD precautions must be taken when handling unit.
- Negative current transients greater than 25 μA and/or reverse voltages >3V can destroy the unit.
- A dry environment should be provided when storing or operating a device with an open diode laser facet at temperatures below the ambient dew point. Failure to do so will cause condensation on the unit and can destroy it.
- Operation in excess of rated power will accelerate device aging.
- Operation at higher temperatures will accelerate device aging, increase threshold current, and lower the slope efficiency. Care should be taken to avoid back-reflections into the device. Failure to do so can destroy the unit.

Single Bar Diode Laser Module

Device Specifications ^{1,2,3,4,5}	28-30% fill factor bars (19 x 140-150 μm emitters)				
	60W 18FF	60W 18FF PulseLife	50W 30FF	80W 28FF	80W 28FF PulseLife
Intended Operation Mode	CW or QCW	Hard pulsed, CW, or QCW	CW or QCW	CW or QCW	Hard pulsed, CW, or QCW
Optical Output Power (W)	40	60	50	80	80
Pulsewidth (μs)	-	-	-	-	-
Duty Cycle (%)	-	-	-	-	-
Fill Factor (%)	30	18	30	28	28
Number of Emitters	19	19	19	19	19
Emitter Width (μm)	150	90	150	140	140
Emitter-to-Emitter Pitch (μm)	500	500	500	500	500
Centroid Wavelength Available ⁶ (nm)	780 to 830	780 to 830	780 to 830	780 to 830	780 to 830
Centroid Wavelength, Standard (nm)(at 25°C)	808 ±3	808 ±3	808 ±3	808 ±3	808 ±3
Spectral Width, Standard (nm)(FWHM)	≤3	≤3	≤3	≤3	≤3
Wavelength Temperature Coefficient (nm/°C)	0.28	0.28	0.28	0.28	0.28
Polarization	TM	TE	TM	TE	TE
Fast Axis Divergence (degrees)(unlensed)(FWHM)	31	29	31	29	29
Fast Axis Divergence (degrees)(lensed)(FWHM)	≤1	≤1	≤1	≤1	≤1
Slow Axis Divergence (degrees)(FWHM)	≤10	≤10	≤10	≤10	≤10
Threshold Current (A)	8 typical	8 typical	10 typical	12 typical	12 typical
Operating Current (A)	≤45 (40 typical)	≤62 (58 typical)	≤55 (50 typical)	≤81 (76 typical)	≤83 (79 typical)
Operating Voltage (V)	≤2.0	≤2.0	≤2.0	≤2.0	≤2.0
Operating Temperature ⁷ (°C)	25	25	25	25	25
Operating Temperature Range (°C)	15 to 35	15 to 35	15 to 35	15 to 35	15 to 35
Storage Temperature Range (°C)	-40 to +60	-40 to +60	-40 to +60	-40 to +60	-40 to +60

Notes:

- Specifications listed here are at beginning of life. Operating current at end of life is 120% the operating current at beginning of life.
- CW operation refers to an operating mode in which the diode lases continuously for multiple minutes at a time or longer
- QCW (quasi-continuous wave) operation refers to an operating mode in which the diode lases only in very short pulses, i.e., <1 ms long, typically at repetition rates of several Hz to kHz.
- Hard pulsed operation refers to an operating mode in which the diode is repeatedly turned on and off - full current to zero current - with pulsewidths longer than several milliseconds.
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 - Centroid wavelength and spectral width requirements other than listed here
 - Optical output powers other than listed here
 - Low smile options.
- Contact factory for availability.
- Operating temperature is measured at the base of the package. The recommended operating temperature range is 15-35°C.

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- ESD precautions must be taken when handling unit.
- Negative current transients greater than 25 μA and/or reverse voltages >3V can destroy the unit.
- A dry environment should be provided when storing or operating a device with an open diode laser facet at temperatures below the ambient dew point. Failure to do so will cause condensation on the unit and can destroy it.
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Single Bar Diode Laser Module

Device Specifications ^{1,2,3,4,5}	90% fill factor bars (60 x 150 µm emitters) 250W QCW PulseLife
Intended Operation Mode	QCW
Optical Output Power (W)	250
Pulsewidth (µs)	≤500
Duty Cycle (%)	≤10
Fill Factor (%)	90
Number of Emitters	60
Emitter Width (µm)	150
Emitter-to-Emitter Pitch (µm)	160
Centroid Wavelength Available ⁶ (nm)	780 to 830
Centroid Wavelength, Standard (nm)(at 25°C)	808 ±3
Spectral Width, Standard (nm)(FWHM)	≤3
Wavelength Temperature Coefficient (nm/°C)	0.28
Polarization	TE
Fast Axis Divergence (degrees)(unlensed)(FWHM)	31
Fast Axis Divergence (degrees)(lensed)(FWHM)	≤1
Slow Axis Divergence (degrees)(FWHM)	≤10
Threshold Current (A)	30 typical
Operating Current (A)	≤265 (250 typical)
Operating Voltage (V)	≤2.4
Operating Temperature ⁷ (°C)	25
Operating Temperature Range (°C)	15 to 35
Storage Temperature Range (°C)	-40 to +60

Notes:

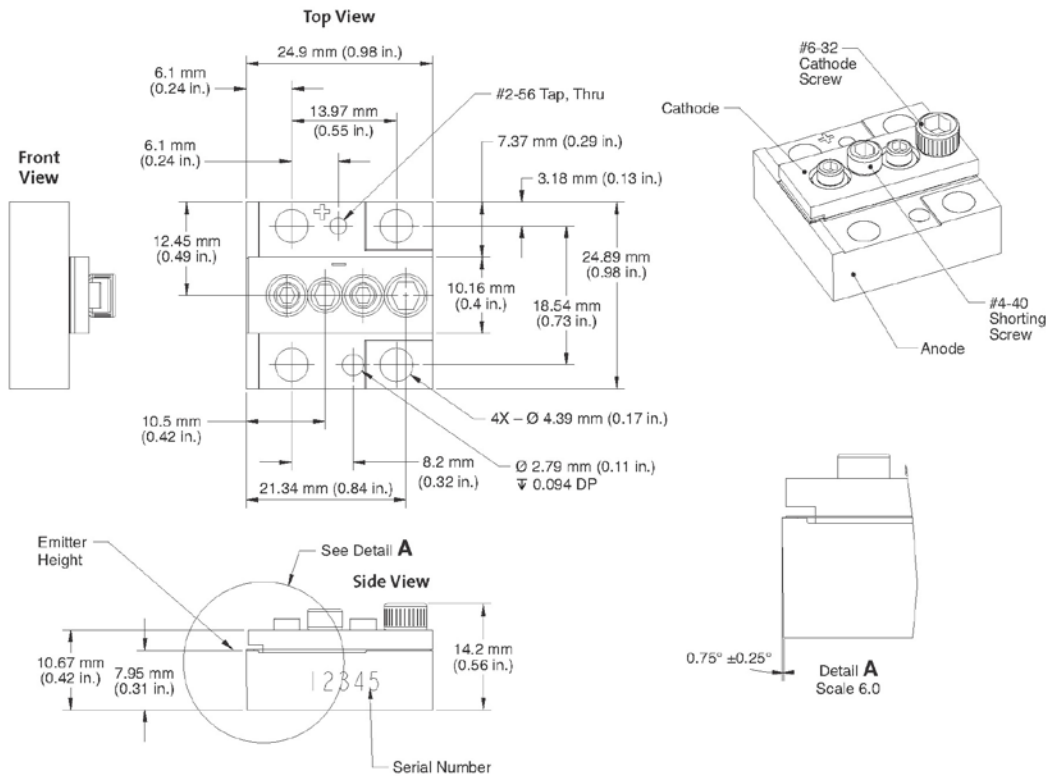
- Specifications listed here are at beginning of life. Operating current at end of life is 120% the operating current at beginning of life.
- CW operation refers to an operating mode in which the diode lases continuously for multiple minutes at a time or longer
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MECHANICAL SPECIFICATIONS

CCP/HCCP



CCP/HCCP, lensed

